

STTH802-Y

Automotive ultrafast recovery diode

Features

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery time
- High junction temperature
- AEC-Q101 qualified

Description

The STTH802-Y uses ST's new 200 V planar Pt doping technology, and is specially suited for switching mode base drive and transistor circuits.

Packaged in DPAK, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection for automotive application.

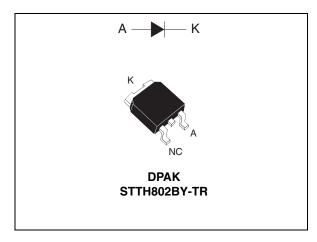


Table 1. Device summary

Symbol	Value
I _{F(AV)}	8 A
V_{RRM}	200 V
T _{j (max)}	175 °C
V _F (typ)	0.8 V
t _{rr} (typ)	17 ns

Characteristics STTH802-Y

1 Characteristics

Table 2. Absolute ratings (limiting values at $T_i = 25$ °C, unless otherwise specified)

Symbol	Parameter			Unit
V _{RRM}	Repetitive peak reverse voltage		200	V
I _{F(RMS)}	Forward rms current			Α
I _{F(AV)}	Average forward current, $\delta = 0.5$ $T_c = 145 ^{\circ}C$		8	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms Sinusoidal}$		100	Α
T _{stg}	Storage temperature range		-65 to + 175	°C
T _j	Maximum operating junction temperature range		-40 to + 175	°C

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	3.2	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Payarea laakaga aurrant	T _j = 25 °C	V - V			6	μA
I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$		6	60	μΑ	
V _E (2)	V _F ⁽²⁾ Forward voltage drop		I _F = 8 A		0.95	1.05	V
v F` ′	Torward voltage drop	T _j = 150 °C	IF - O A		0.8	0.90	'

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation: $P = 0.73 \times I_{F(AV)} + 0.021 I_{F}^{2}_{(RMS)}$

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

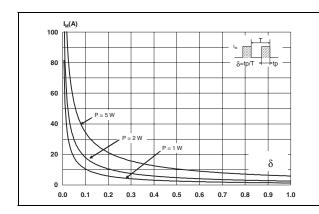
STTH802-Y Characteristics

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
	Povorce recovery time	$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		25	30	ns
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		17	22	
I _{RM}	Reverse recovery current	$I_F = 8 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s}, \ V_R = 160 \text{ V}, T_j = 125 ^{\circ}\text{C}$		5.5	7	Α
t _{fr}	Forward recovery time	$I_F = 8 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25 ^{\circ}\text{C}$		150		ns
V_{FP}	Forward recovery voltage	$I_F = 8 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s},$ $T_j = 25 ^{\circ}\text{C}$		1.5		٧

Figure 1. Peak current versus duty cycle

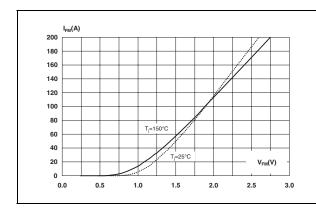
Figure 2. Forward voltage drop versus forward current (typical values)

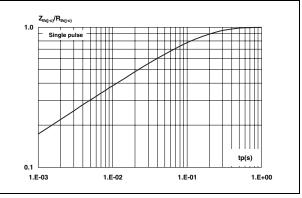


200 180 160 140 120 100 40 20 $V_{\text{FM}}(V)$ 0.5 1.5 2.0 3.0 0.0 1.0 2.5

Figure 3. Forward voltage drop versus forward current (maximum values)

Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration

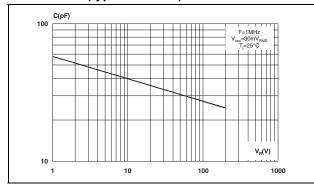




Characteristics STTH802-Y

Figure 5. Junction capacitanceversus reverse applied voltage (typical values)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)



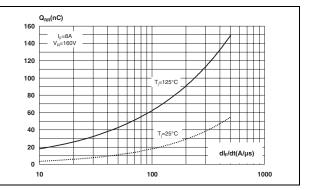
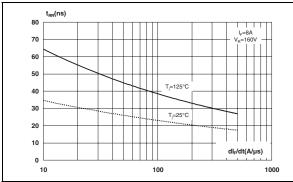


Figure 7. Reverse recovery time versus dI_F/dt Figure 8. Peak reverse recovery current (typical values)



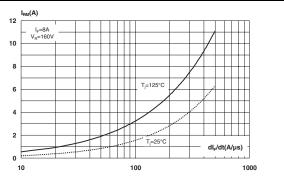
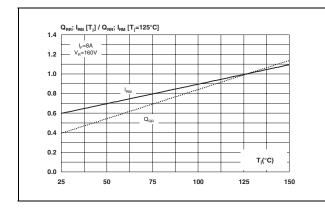
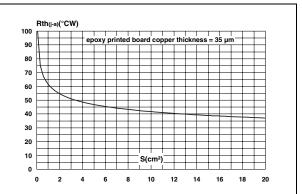


Figure 9. Dynamic parameters versus junction temperature

Figure 10. Thermal resistance, junction to ambient, versus copper surface under tab





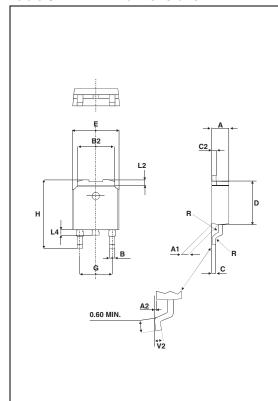
57

2 Package information

- Epoxy meets UL94, V0
- Lead-free package

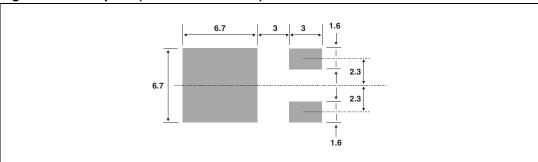
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 6. DPAK dimensions



	Dimensions				
Ref.	Ref. Millimeter		Inches		
	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
Е	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.03	1 typ.	
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

Figure 11. Footprint (dimensions in mm)



Ordering information STTH802-Y

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH802BY-TR	STTH802Y	DPAK	0.3 g	2500	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
10-Mar-2011	1	First issue.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time. without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2011 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

